Carbon 120 (2017) 71-76

Contents lists available at ScienceDirect

Carbon

journal homepage: www.elsevier.com/locate/carbon

Efficient hole-conductor-free, fully printable mesoscopic perovskite solar cells with carbon electrode based on ultrathin graphite

Miao Duan¹, Yaoguang Rong¹, Anyi Mei, Yue Hu, Yusong Sheng, Yanjun Guan, Hongwei Han^{*}

Michael Grätzel Center for Mesoscopic Solar Cells, Wuhan National Laboratory for Optoelectronics, School of Optical and Electronic Information, Huazhong University of Science and Technology, Wuhan 430074, Hubei, PR China

A R T I C L E I N F O

Article history: Received 23 March 2017 Received in revised form 5 May 2017 Accepted 6 May 2017 Available online 7 May 2017

ABSTRACT

Ultrathin graphite has been applied in hole-conductor-free, fully printable mesoscopic perovskite solar cells as counter electrode. It was found that ultrathin graphite effectively increased the specific surface area of the carbon layer without sacrificing the conductivity. The large specific surface area facilitated the hole collection from the perovskite to carbon layer, correspondingly decreased the charge transfer resistance at the perovskite/carbon interface. Besides, the penetration of perovskite precursor solution in the carbon layer was accelerated due to the highly interconnected channels. As a result, the power conversion efficiency of the printable mesoscopic perovskite solar cell was significantly improved from 12.63% to 14.07% by incorporating ultrathin graphite instead of bulk graphite.

© 2017 Elsevier Ltd. All rights reserved.

1. Introduction

Organic-inorganic hybrid lead halide perovskite solar cells (PSCs) have become increasingly attractive in the field of photovoltaics due to their simple fabrication and high power conversion efficiency (PCE) [1-3]. Recently, the efficiency of PSC of 22.1% approaching the poly silicon solar cell has been certified by the National Renewable Energy Laboratory (NREL) [4], which indicates their great potential in photovoltaics markets. A typical PSC usually employs device architecture of TiO₂/Perovskite/HTM/Au, in which the spiro-OMeTAD or PTAA are the most frequent choice of hole transport materials (HTM) [2,5,6]. However, the cost of spiro-OMeTAD or PTAA over ten times of the gold and the stability of such HTM under ambient air become a major concern for the development of PSCs [7]. Fortunately, besides the strong absorption coefficient, the typical perovskite materials such as MAPbI₃ appears high hole mobility, therefore it could be used as both of absorber and HTM material to achieve a simple and low-cost HTMfree PSCs [8].

Meanwhile, counter electrodes play a critical role in regulating heterojunction solar cells performance by collecting carriers [9,10].

¹ These authors contributed equally.

The nobel metal Au is the most efficient and thus widely used as counter electrode materials. But the expensive Au would increase manufacture cost of cells, which limits the industrialization progress. Therefore, much effort has been made to replace Au-based electrodes. In particular, the low-cost carbon materials possessing high electricity conductivity have become the most important candidate. In precious study, all sorts of carbon materials containing graphite, candle soot, CNT and mesoporous carbon were investigated. Y. Yang et al. applied flexible graphite sheet as carbon electrode in PSCs device, presenting a PCE of 10.2% [11]. Z. Wei et al. developed clamping perovskite solar cells using candle soot as hole extraction electrodes [12]. Z. Li et al. used laminated carbon nanotube networks as hole collection for perovskite solar cells and obtained a PCE of 6.29% [13]. Though the most studies focused on the planar carbon electrode based PSCs, the poor contact between perovskite and carbon electrode and the unmanageable thickness between the electron collecting layer and the carbon electrode will limit the repeatability and efficiency of the device.

To meet with the demand of low-cost, high efficient and repeatable photovoltaic device, a hole-conductor-free fully printable mesoscopic perovskite solar cells (MPSCs) have been developed in our group [14,15], which employs a triple layer of mesoporous TiO₂, ZrO₂ and carbon as a scaffold and is infiltrated by the perovskite as a light harvester. The thickness between the electron collecting layer and the carbon electrode is accurately controlled by the ZrO₂ spacer layer. No hole conductor or Au





Carbon

^{*} Corresponding author.

E-mail address: hongwei.han@mail.hust.edu.cn (H. Han).

reflector is employed [16–18]. Particularly, a new mixed-cation perovskite $(5-AVA)_x(MA)_{1-x}PbI_3$ to replace MAPbI_3 was applied in printable MPSCs and achieved a certified PCE of 12.84% with long stabilization in ambient air [14]. However, the used bulk graphite has a thick-layered structure with a small specific surface area. The larger surface area of the carbon layer brings the more highly interconnected channels, which is beneficial for the penetration of perovskite precursor solution. Therefore, it is worth developing the large surface area carbon layer without sacrificing the conductivity in PSC device.

In this work, we firstly utilized ultrathin graphite (UG) to replace bulk graphite (BG) to construct mesoporous conductive carbon films with a large specific surface area and then applied in MPSCs devices. Herein, the UG mixed with carbon black was used as counter electrode of the printable MPSC. In contrast with the bulk graphite/carbon black electrode (BGE), the ultrathin graphite/carbon black electrode (UGE) possessing a specific surface area of 202.24 m²g⁻¹ exhibited a comparable square resistance at the same film thickness. The electrochemical impedance spectroscopy analysis of the UGE based device exhibited a lower charge resistance at the perovskite/carbon interface. Furthermore, the UGE had a better hole extraction ability and shorten the PL lifetime from 1.03 to 0.698 ns according to time-resolved photoluminescence measurement. Therefore, the MPSCs based on UGE achieved a high FF of 0.68 and thereby a higher efficiency of 14.07%.

2. Experimental

2.1. Fabrication of carbon paste

The UG was prepared by exfoliation of bulk graphite using wet ball milling as reported literature [19]. The carbon pastes were prepared by the following procedure as reported by us previously [20]. In brief, the BGs and UGs were mixed with carbon black in terpineol solution, respectively. The hydroxypropyl cellulose was then added into the solution, followed by stirring vigorously via ball milling for 10 h.

2.2. Device fabrication

The fully printable MPSCs were prepared as reported [14]. The laser-patterned F-doped SnO₂ (FTO) glass was ultrasonically cleaned with detergent, deionized water and ethanol successively. A TiO₂ compact layer was then deposited on FTO substrate by spray pyrolysis at 450 °C with diisopropoxide bis(acetylacetonate) solution and sintered for 30 min. A mesoporous TiO₂ layer was screen-printed on the compact layer and sintered at 500 °C for 40 min. Subsequently, a mesoporous ZrO₂ space layer was deposited on the top of mesoporous TiO₂ layer by screen-printing and sintered at 500 °C for 40 min. After cooling to room temperature, a mesoporous carbon layer was printed on the ZrO₂ space layer and sintered at 400 °C for 30 min. Finally, a 4 μ L (5-AVA)_x(MA)_{1-x}Pbl₃ perovskite precursor solution was dipped on the top of the carbon electrode. The device was accomplished after drying at 50 °C for 1 h.

2.3. Characterization

The morphology of samples was observed by a field-emission scanning electronmicroscope (SEM) (FEI Nova NanoSEM450) and transmission electron microscopy (TEM) (FEI Tecnai G2 20). The surface topography of UGs was analyzed by atomic force microscope (AFM) (Veeco Multimode) in the tapping mode. The Raman spectra of the BG and UG were obtained by Horiba Jobin Yvon LabRAM HR800 Raman system with the 532 nm wavelength of a 50 mW Nd-YAG laser at room temperature. The Brunauer–Emmett -Teller (BET) of samples was characterized by an Accelerated Surface Area and Porosimetry System (ASAP) 2020. The electrical conductivity of carbon films was obtained by a KDY-1 four point probe analyzer. The film thickness was measured by using profilometer (Dektak XT, Brucker). The wetting property of films was performed on a KinoSL200B contact angle goniometer. The photocurrent density-voltage characteristics were recorded by a Keithley 2400 sourcemeter under the air mass 1.5 (AM1.5) illumination at 100 mWcm⁻² using an Oriel 91192 solar simulator (Newport, USA). Electrochemical impedance spectroscopy (EIS) of the devices was performed on ZAHNER ENNIUM electrochemical workstations in the frequency range from 100 mHz to 4 MHz. The steady-state photoluminescence (PL) spectra were measured by a Horiba Jobin Yvon LabRAM HR800s with a 532 nm wavelength excitation source. The time-resolved photoluminescence (TRPL) was measured at 760 nm using excitation with a 478 nm light pulse from Delta Flex Fluorescence Lifetime System (Horiba Scientific Com., Japan). The scatterer (Ludox suspension) was used as the instrument response function for deconvolution of the spectral value

3. Results and discussion

The SEM image shown in Fig. 1 presents the morphology of UG and BG, respectively. The ultrathin graphite sheets tend to stick together to form fluffy agglomerate as shown in Fig. 1a. A magnified image of the agglomerates is shown in Fig. 1b, it can be clearly seen that UG has a diameter ranging from 5 to 15 μ m with coadiacent ultrathin graphite sheets, the size of which is similar to the BG (Fig. 1c-d). It is noted that edges of ultrathin graphite sheets are folded, indicating a small thickness. Fig. S1a displays the TEM image of partial ultrathin graphite sheets. Obviously, UGs have a highly transparent appearance with few-layer graphene, like transparent silk. To further investigate the thickness of UG, the AFM analysis in Fig. S1b is carried out. The vertical distance between the silicon substrate and the UG surface is regarded as the thickness of UG. From the height profiles (inset, Fig. S1b), it can be seen that the thickness of UG is approximately 2 nm, which is estimated to be less 10 layers of graphene [21]. Fig. S2 presents Raman spectra of the UG and BG. In general, the first-order Raman spectra of graphite materials present two intense feature bands. The G band at ~1580 cm $^{-1}$ is corresponding to the E_{2g} phonon of sp²carbon atoms and the D band at ~1350 cm⁻¹ reflects the amount of disorder (compared to G band). In addition, the overtone of the D band, 2D band, is located at ~2700 cm⁻¹. The 2D peak at 2693 cm⁻¹ of UG is about 21 cm⁻¹lower than that of the bulk graphite, which is consistent with the reported data of few-layer graphene [22]. In addition, the D/G peak intensity ratio of UG is about 0.13, much smaller than the value of graphene synthesized from the chemical reduction of graphene oxide [23], indicating UGs prepared by mechanical exfoliation method possibly have less structure defect and improved electrical conductivity. Fig. S3 shows low and high magnification images for the surface morphology of carbon electrodes based on UG and BG after sintering at 400 °C, respectively. Obviously, the surface of UGE is relatively rough (Fig. S3a) with massive ultrathin graphite vertically standing the film (Fig. S3b), which is beneficial for building conductive network structure.

Fig. 2a shows the N₂ absorption and desorption curves of the carbon electrode (CE) based on BG and UG. Calculated by BJH (Barrett-Joyner-Halenda) method, the specific surface area value of UGE and BGE is 202.24 and 69.01 m^2g^{-1} , respectively. The large specific surface area of the UGE provides more effective contact between the perovskite and carbon film. Therefore, the increase of specific surface area for the UGE contributes to hole collection from

Download English Version:

https://daneshyari.com/en/article/5431626

Download Persian Version:

https://daneshyari.com/article/5431626

Daneshyari.com